ANALOG DEVICES

3.75 kV, 7-Channel Digital Isolator for SPI

Preliminary Technical Data

ADuM3154

FEATURES

Supports up to 17 MHz SPI clock speed
4 high speed, low propagation delay, SPI signal isolation channels
Supports up to 4 slave devices
20-lead SSOP package with 5 mm creepage
High temperature operation: 125°C
High common-mode transient immunity: >25 kV/μs
Safety and regulatory approvals
   UL recognition per UL 1577 (pending)
      3750 V rms for 1 minute
   CSA Component Acceptance Notice 5A (pending)
   VDE certificate of conformity (pending)
      DIN V VDE V 0884-10 (VDE V 0884-10):2006-12
      V_{IORM} = 560 V peak

APPLICATIONS

Industrial programmable logic controllers (PLCs)
Sensor isolation

GENERAL DESCRIPTION

The ADuM3154[1] is a SPIsolator™ digital isolator optimized for a serial peripheral interface (SPI) that includes support for up to four slave devices. Based on the Analog Devices, Inc., iCoupler® chip scale transformer technology, the low propagation delay and jitter in the CLK, MO/SI, MI/SO, and $\overline{SS}$ channels support SPI clock rates of up to 17 MHz.

The ADuM3154 isolator also provides a slave select multiplexing system that allows up to four slave devices to be serviced from one isolator. The slave select system propagates to the desired output with full propagation speed, allowing tight timing control. The isolated $\overline{SS}$ multiplexer is addressed through a 250 kbps low speed dual port with 2.5 μs of setup time.

Table 1. Related Products

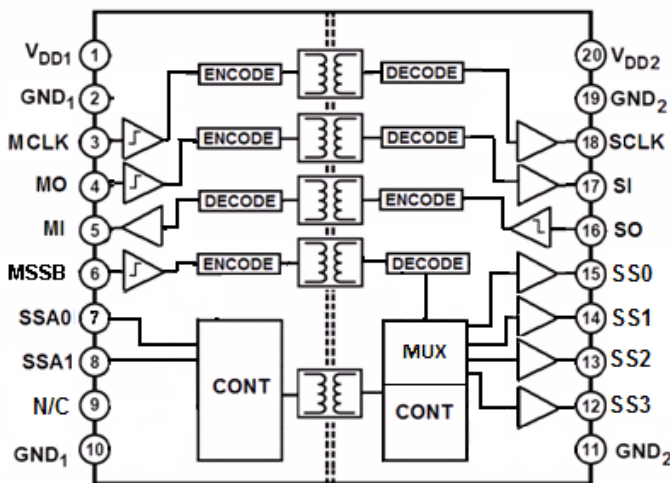| Product	Description
ADuM3150	3.75 kV, high speed clock delayed SPI isolator
ADuM3151	3.75 kV, multichannel SPI isolator
ADuM3152	3.75 kV, multichannel SPI isolator
ADuM3153	3.75 kV, multichannel SPI isolator

FUNCTIONAL BLOCK DIAGRAM

Figure 1.

[1] Protected by U.S. Patents 5,952,849; 6,873,065; 6,903,578; and 7,075,329. Other patents are pending.

Rev. PrA

TABLE OF CONTENTS

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS—5 V OPERATION

All typical specifications are at T_A = 25°C and V_{DD1} = V_{DD2} = 5 V. Minimum and maximum specifications apply over the entire recommended operation range: 4.5 V ≤ V_{DD1} ≤ 5.5 V, 4.5 V ≤ V_{DD2} ≤ 5.5 V, −40°C ≤ T_A ≤ +125°C, unless otherwise noted. Switching specifications are tested with C_L = 15 pF and CMOS signal levels, unless otherwise noted.

Table 2. Switching Specifications

Parameter	Symbol	A Grade			B Grade			Unit	Test Conditions/Comments
		Min	Typ	Max	Min	Typ	Max		
MCLK, MO, SO									
SPI Clock Rate	SPI_{MCLK}			1			17	MHz	
Data Rate Fast (MO, SO)	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			25		12	14	ns	50% input to 50% output
Pulse Width	PW	100			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			2	ns	$|t_{PLH} − t_{PHL}|$
Codirectional Channel Matching[1]	t_{PSKCD}			3			2	ns	
Jitter, High Speed	J_{HS}		1			1		ns	
$\overline{MSS}$									
Data Rate Fast	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}		21	25		21	25	ns	50% input to 50% output
Pulse Width	PW	100			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			3	ns	$|t_{PLH} − t_{PHL}|$
Setup Time[2]	$\overline{MSS}_{SETUP}$	1.5			10			ns	
Jitter, High Speed	J_{HS}		1			1		ns	
SSA0, SSA1									
Data Rate Slow	DR_{SLOW}			250			250	kbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}	0.1		2.6	0.1		2.6	µs	50% input to 50% output
Pulse Width	PW	4			4			µs	Within PWD limit
Jitter, Low Speed	J_{LS}			2.5			2.5	µs	
SSAx[3] Minimum Input Skew[4]	$t_{SSAx\ SKEW}$[3]	10			10			ns	

[1] Codirectional channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier.
[2] The $\overline{MSS}$ signal is glitch filtered in both speed grades, where as the other fast signals are not glitch filtered in the B grade. To guarantee that $\overline{MSS}$ reaches the output ahead of another fast signal, set up $\overline{MSS}$ prior to the competing signal by different times depending on speed grade.
[3] SSAx = SSA1 or SSA2.
[4] An internal asynchronous clock not available to users samples the low speed signals. If edge sequence in codirectional channels is critical to the end application, the leading pulse must be at least 1 $t_{SSAx\ SKEW}$ time ahead of a later pulse to guarantee the correct order or simultaneous arrival at the output.

Table 3. For All Models[1, 2, 3]

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SUPPLY CURRENT	I_{DD1}		4.0	5.0	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		6.0	10.0	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD1}		4.0	5.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		6.0	10.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
DC SPECIFICATIONS						
MCLK, $\overline{MSS}$, MO, SO, SSA0, SSA1						
Logic High Input Threshold	V_{IH}	0.7 V_{DDx}			V	
Logic Low Input Threshold	V_{IL}			0.3 V_{DDx}	V	
Input Hysteresis	V_{IHYST}		500		mV	
Input Current per Channel	I_I	−1	+0.01	+1	µA	0 V ≤ V_{INPUT} ≤ V_{DDx}

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SCLK, MI, SI, SS0, SS1, SS2, SS3						
Logic High Output Voltages	V_{OH}	$V_{DDx} - 0.1$	5.0		V	$I_{OUTPUT} = -20\ \mu A$, $V_{INPUT} = V_{IH}$
		$V_{DDx} - 0.4$	4.8		V	$I_{OUTPUT} = -4\ mA$, $V_{INPUT} = V_{IH}$
Logic Low Output Voltages	V_{OL}		0.0	0.1	V	$I_{OUTPUT} = 20\ \mu A$, $V_{INPUT} = V_{IL}$
			0.2	0.4	V	$I_{OUTPUT} = 4\ mA$, $V_{INPUT} = V_{IL}$
V_{DD1}, V_{DD2} Undervoltage Lockout	UVLO			2.6	V	
Supply Current for High Speed Channel						
Dynamic Input Supply Current	$I_{DDI(D)}$		0.09		mA/Mbps	
Dynamic Output Supply Current	$I_{DDO(D)}$		0.02		mA/Mbps	
Supply Current for All Low Speed Channels						
Quiescent Input Supply Current	$I_{DDI(Q)}$		4.5		mA	
Quiescent Output Supply Current	$I_{DDO(Q)}$		5.5		mA	
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity[4]	|CM|	25	35		kV/µs	$V_{IINPUT} = V_{DDx}$, $V_{CM} = 1000\ V$, transient magnitude = 800 V

[1] $V_{DDx} = V_{DD1}$ or V_{DD2}.
[2] V_{INPUT} is the input voltage of any of the MCLK, $\overline{MSS}$, MO, SO, SSA0, or SSA1 pins.
[3] I_{OUTPUT} is the output current of any of the SCLK, MI, SI, SS0 SS1, SS2, or SS3 pins.
[4] |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining output voltages within the V_{OH} and V_{OL} limits. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—3.3 V OPERATION

All typical specifications are at T_A = 25°C and V_{DD1} = V_{DD2} = 3.3 V. Minimum and maximum specifications apply over the entire recommended operation range: 3.0 V ≤ V_{DD1} ≤ 3.6 V, 3.0 V ≤ V_{DD2} ≤ 3.6 V, −40°C ≤ T_A ≤ +125°C, unless otherwise noted. Switching specifications are tested with C_L = 15 pF and CMOS signal levels, unless otherwise noted.

Table 4. Switching Specifications

Parameter	Symbol	A Grade Min	A Grade Typ	A Grade Max	B Grade Min	B Grade Typ	B Grade Max	Unit	Test Conditions/Comments
MCLK, MO, SO									
SPI Clock Rate	SPI_{MCLK}			1			12.5	MHz	
Data Rate Fast (MO, SO)	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			30			20	ns	50% input to 50% output
Pulse Width	PW	100			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			3	ns	$\lvert t_{PLH} - t_{PHL}\rvert$
Codirectional Channel Matching[1]	t_{PSKCD}			4			2	ns	
Jitter, High Speed	J_{HS}		1			1		ns	
$\overline{MSS}$									
Data Rate Fast	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			30			30	ns	50% input to 50% output
Pulse Width	PW	100			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			3	ns	$\lvert t_{PLH} - t_{PHL}\rvert$
Setup Time[2]	$\overline{MSS}_{SETUP}$	1.5			10			ns	
Jitter, High Speed	J_{HS}		1			1		ns	
SSA0, SSA1									
Data Rate Slow	DR_{SLOW}			250			250	kbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}	0.1		2.6	0.1		2.6	µs	50% input to 50% output
Pulse Width	PW	4			4			µs	Within PWD limit
Jitter, Low Speed	J_{LS}			2.5			2.5	µs	
SSAx[3] Minimum Input Skew[4]	$t_{SSAx\ SKEW}$[3]	10			10			ns	

[1] Codirectional channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier.

[2] The $\overline{MSS}$ signal is glitch filtered in both speed grades, whereas the other fast signals are not glitch filtered in the B grade. To guarantee that $\overline{MSS}$ reaches the output ahead of another fast signal, set up $\overline{MSS}$ prior to the competing signal by different times depending on speed grade.

[3] SSAx = SSA1 or SSA2.

[4] An internal asynchronous clock not available to users samples the low speed signals. If edge sequence in codirectional channels is critical to the end application, the leading pulse must be at least 1 $t_{SSAx\ SKEW}$ time ahead of a later pulse to guarantee the correct order or simultaneous arrival at the output.

Table 5. For All Models[1, 2, 3]

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SUPPLY CURRENT	I_{DD1}		3.4	5.0	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		5.0	7.0	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD1}		11.7	14.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		10.0	13.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
DC SPECIFICATIONS						
MCLK, $\overline{MSS}$, MO, SO, SSA0, SSA1						
Logic High Input Threshold	V_{IH}	0.7 V_{DDx}			V	
Logic Low Input Threshold	V_{IL}			0.3 V_{DDx}	V	
Input Hysteresis	V_{IHYST}		500		mV	
Input Current per Channel	I_I	−1	+0.01	+1	µA	0 V ≤ V_{INPUT} ≤ V_{DDx}

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SCLK, MI, SI, SS0, SS1, SS2, SS3						
Logic High Output Voltages	V_{OH}	$V_{DDx} - 0.1$	5.0		V	$I_{OUTPUT} = -20\ \mu A$, $V_{INPUT} = V_{IH}$
		$V_{DDx} - 0.4$	4.8		V	$I_{OUTPUT} = -4\ mA$, $V_{INPUT} = V_{IH}$
Logic Low Output Voltages	V_{OL}		0.0	0.1	V	$I_{OUTPUT} = 20\ \mu A$, $V_{INPUT} = V_{IL}$
			0.2	0.4	V	$I_{OUTPUT} = 4\ mA$, $V_{INPUT} = V_{IL}$
V_{DD1}, V_{DD2} Undervoltage Lockout	UVLO		2.6		V	
Supply Current for High Speed Channel						
Dynamic Input Supply Current	$I_{DDI(D)}$		0.09		mA/Mbps	
Dynamic Output Supply Current	$I_{DDO(D)}$		0.02		mA/Mbps	
Supply Current for All Low Speed Channels						
Quiescent Input Supply Current	$I_{DDI(Q)}$		2.8		mA	
Quiescent Output Supply Current	$I_{DDO(Q)}$		4.7		mA	
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity[4]	|CM|	25	35		kV/μs	$V_{IINPUT} = V_{DDx}$, $V_{CM} = 1000\ V$, transient magnitude = 800 V

[1] $V_{DDx} = V_{DD1}$ or V_{DD2}.
[2] V_{INPUT} is the input voltage of any of the MCLK, $\overline{MSS}$, MO, SO, SSA0, or SSA1 pins.
[3] I_{OUTPUT} is the output current of any of the SCLK, MI, SI, SS0 SS1, SS2, or SS3 pins.
[4] |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining output voltages within the V_{OH} and V_{OL} limits. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges..

ELECTRICAL CHARACTERISTICS—MIXED 5 V/3.3 V OPERATION

All typical specifications are at T_A = 25°C and V_{DD1} = 5 V, V_{DD2} = 3.3 V. Minimum and maximum specifications apply over the entire recommended operation range: 4.5 V ≤ V_{DD1} ≤ 5.5 V, 3.0 V ≤ V_{DD2} ≤ 3.6 V, and −40°C ≤ T_A ≤ +125°C, unless otherwise noted. Switching specifications are tested with C_L = 15 pF and CMOS signal levels, unless otherwise noted.

Table 6. Switching Specifications

Parameter	Symbol	A Grade			B Grade			Unit	Test Conditions/Comments
		Min	Typ	Max	Min	Typ	Max		
MCLK, MO, SO									
SPI Clock Rate	SPI_{MCLK}			1			15.6	MHz	
Data Rate Fast (MO, SO)	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			27			16	ns	50% input to 50% output
Pulse Width	PW	25			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			3	ns	$\|t_{PLH} - t_{PHL}\|$
Codirectional Channel Matching[1]	t_{PSKCD}			3			2	ns	
Jitter, High Speed	J_{HS}		1			1		ns	
$\overline{MSS}$									
Data Rate Fast	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			27			26	ns	50% input to 50% output
Pulse Width	PW	25			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			3	ns	$\|t_{PLH} - t_{PHL}\|$
Setup Time[2]	$\overline{MSS}_{SETUP}$	1.5			10			ns	
Jitter, High Speed	J_{HS}		1			1		ns	
SSA0, SSA1									
Data Rate Slow	DR_{SLOW}			250			250	kbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}	0.1		2.6	0.1		2.6	µs	50% input to 50% output
Pulse Width	PW	4			4			µs	Within PWD limit
Jitter, Low Speed	J_{LS}			2.5			2.5	µs	$\|t_{PLH} - t_{PHL}\|$
SSAx[3] Minimum Input Skew[4]	$t_{SSAx\ SKEW}$[3]	10			10			ns	

[1] Codirectional channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier.

[2] The $\overline{MSS}$ signal is glitch filtered in both speed grades, while the other fast signals are not glitch filtered in the B grade. To guarantee that $\overline{MSS}$ reaches the output ahead of another fast signal, set up $\overline{MSS}$ prior to the competing signal by different times depending on speed grade.

[3] SSAx = SSA1 or SSA2.

[4] An internal asynchronous clock not available to users samples the low speed signals. If edge sequence in codirectional channels is critical to the end application, the leading pulse must be at least 1 $t_{SSAx\ SKEW}$ time ahead of a later pulse to guarantee the correct order or simultaneous arrival at the output.

Table 7. For All Models[1, 2, 3]

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SUPPLY CURRENT						
	I_{DD1}		4.8	6.5	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		5.0	7.2	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD1}		14.0	17.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		10.0	12.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
DC SPECIFICATIONS						
MCLK, $\overline{MSS}$, MO, SO, SSA0, SSA1						
Logic High Input Threshold	V_{IH}	0.7 V_{DDx}			V	
Logic Low Input Threshold	V_{IL}			0.3 V_{DDx}	V	
Input Hysteresis	V_{IHYST}		500		mV	
Input Current per Channel	I_I	−1	+0.01	+1	µA	0 V ≤ V_{INPUT} ≤ V_{DDX}

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SCLK, MI, SI, SS0, SS1, SS2, SS3						
Logic High Output Voltages	V_{OH}	$V_{DDx} - 0.1$	5.0		V	$I_{OUTPUT} = -20\ \mu A$, $V_{INPUT} = V_{IH}$
		$V_{DDx} - 0.4$	4.8		V	$I_{OUTPUT} = -4$ mA, $V_{INPUT} = V_{IH}$
Logic Low Output Voltages	V_{OL}		0.0	0.1	V	$I_{OUTPUT} = 20\ \mu A$, $V_{INPUT} = V_{IL}$
			0.2	0.4	V	$I_{OUTPUT} = 4$ mA, $V_{INPUT} = V_{IL}$
V_{DD1}, V_{DD2} Undervoltage Lockout	UVLO		2.6		V	
Supply Current for High Speed Channel						
Dynamic Input Supply Current	$I_{DDI(D)}$		0.09		mA/Mbps	
Dynamic Output Supply Current	$I_{DDO(D)}$		0.02		mA/Mbps	
Supply Current for All Low Speed Channels						
Quiescent Input Supply Current	$I_{DDI(Q)}$		4.0		mA	
Quiescent Output Supply Current	$I_{DDO(Q)}$		4.7		mA	
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity[4]	|CM|	25	35		kV/µs	$V_{IINPUT} = V_{DDx}$, $V_{CM} = 1000$ V, transient magnitude = 800 V

[1] $V_{DDx} = V_{DD1}$ or V_{DD2}.
[2] V_{INPUT} is the input voltage of any of the MCLK, $\overline{MSS}$, MO, SO, SSA0, or SSA1 pins.
[3] I_{OUTPUT} is the output current of any of the SCLK, MI, SI, SS0 SS1, SS2, or SS3 pins.
[4] |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining output voltages within the V_{OH} and V_{OL} limits. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—MIXED 3.3 V/5 V OPERATION

All typical specifications are at T_A = 25°C and V_{DD1} = 3.3 V, V_{DD2} = 5 V. Minimum and maximum specifications apply over the entire recommended operation range: 3.0 V ≤ V_{DD1} ≤ 3.6 V, 4.5 V ≤ V_{DD2} ≤ 5.5 V, and −40°C ≤ T_A ≤ +125°C, unless otherwise noted. Switching specifications are tested with C_L = 15 pF and CMOS signal levels, unless otherwise noted.

Table 8. Switching Specifications

Parameter	Symbol	A Grade			B Grade			Unit	Test Conditions/Comments
		Min	Typ	Max	Min	Typ	Max		
MCLK, MO, SO									
SPI Clock Rate	SPI_{MCLK}			1			15.6	MHz	
Data Rate Fast (MO, SO)	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			27			16	ns	50% input to 50% output
Pulse Width	PW	100			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			3			3	ns	$\|t_{PLH} - t_{PHL}\|$
Codirectional Channel Matching[1]	t_{PSKCD}			5			2	ns	
Jitter, High Speed	J_{HS}		1			1		ns	
$\overline{MSS}$									
Jitter			1			1		ns	
Data Rate Fast	DR_{FAST}			2			34	Mbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}			27		21	27	ns	50% input to 50% output
Pulse Width	PW	100			12.5			ns	Within PWD limit
Pulse Width Distortion	PWD			2			3	ns	$\|t_{PLH} - t_{PHL}\|$
Setup Time[2]	$\overline{MSS}_{SETUP}$	1.5			10			ns	
Jitter, High Speed	J_{HS}		1			1		ns	
SSA0, SSA1									
Data Rate Slow	DR_{SLOW}			250			250	kbps	Within PWD limit
Propagation Delay	t_{PHL}, t_{PLH}	0.1		2.6	0.1		2.6	µs	50% input to 50% output
Pulse Width	PW	4			4			µs	Within PWD limit
Jitter, Low Speed	J_{LS}			2.5			2.5	µs	$\|t_{PLH} - t_{PHL}\|$
SSAx[3] Minimum Input Skew[4]	$t_{SSAx\ SKEW}$[3]	10			10			ns	

[1] Codirectional channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier.

[2] The $\overline{MSS}$ signal is glitch filtered in both speed grades, while the other fast signals are not glitch filtered in the B grade. To guarantee that $\overline{MSS}$ reaches the output ahead of another fast signal, set up $\overline{MSS}$ prior to the competing signal by different times depending on speed grade.

[3] SSAx = SSA1 or SSA2.

[4] An internal asynchronous clock not available to users samples the low speed signals. If edge sequence in codirectional channels is critical to the end application, the leading pulse must be at least 1 $t_{SSAx\ SKEW}$ time ahead of a later pulse to guarantee the correct order or simultaneous arrival at the output.

Table 9. For All Models[1, 2, 3]

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SUPPLY CURRENT	I_{DD}		3.5	5.0	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		6.5	10.0	mA	C_L = 15 pF, DR_{FAST} = 1 MHz, DR_{SLOW} = 0 MHz
	I_{DD}		11.7	14.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
	I_{DD2}		13.4	17.0	mA	C_L = 15 pF, DR_{FAST} = 17 MHz, DR_{SLOW} = 0 MHz
DC SPECIFICATIONS						
MCLK, $\overline{MSS}$, MO, SO, SSA0, SSA1						
Logic High Input Threshold	V_{IH}	0.7 V_{DDx}			V	
Logic Low Input Threshold	V_{IL}			0.3 V_{DDx}	V	
Input Hysteresis	V_{IHYST}		500		mV	
Input Current per Channel	I_I	−1	+0.01	+1	µA	0 V ≤ V_{INPUT} ≤ V_{DDx}

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
SCLK, MI, SI, SS0, SS1, SS2, SS3						
Logic High Output Voltages	V_{OH}	$V_{DDx} - 0.1$	5.0		V	$I_{OUTPUT} = -20\ \mu A$, $V_{INPUT} = V_{IH}$
		$V_{DDx} - 0.4$	4.8		V	$I_{OUTPUT} = -4\ mA$, $V_{INPUT} = V_{IH}$
Logic Low Output Voltages	V_{OL}		0.0	0.1	V	$I_{OUTPUT} = 20\ \mu A$, $V_{INPUT} = V_{IL}$
			0.2	0.4	V	$I_{OUTPUT} = 4\ mA$, $V_{INPUT} = V_{IL}$
Undervoltage Lockout V_{DD1}, V_{DD2}	UVLO		2.6		V	
Supply Current for High Speed Channel						
Dynamic Input Supply Current	$I_{DDI(D)}$		0.09		mA/Mbps	
Dynamic Output Supply Current	$I_{DDO(D)}$		0.02		mA/Mbps	
Supply Current for All Low Speed Channels						
Quiescent Input Supply Current	$I_{DDI(Q)}$		2.8		mA	
Quiescent Output Supply Current	$I_{DDO(Q)}$		6.4		mA	
AC SPECIFICATIONS						
Output Rise/Fall Time	t_R/t_F		2.5		ns	10% to 90%
Common-Mode Transient Immunity[4]	|CM|	25	35		kV/μs	$V_{IINPUT} = V_{DDx}$, $V_{CM} = 1000\ V$, transient magnitude = 800 V

[1] $V_{DDx} = V_{DD1}$ or V_{DD2}.
[2] V_{INPUT} is the input voltage of any of the MCLK, $\overline{MSS}$, MO, SO, SSA0, or SSA1 pins.
[3] I_{OUTPUT} is the output current of any of the SCLK, MI, SI, SS0 SS1, SS2, or SS3 pins.
[4] |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining output voltages within the V_{OH} and V_{OL} limits. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

PACKAGE CHARACTERISTICS

Table 10.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
Resistance (Input to Output)[1]	R_{I-O}		10^{12}		Ω	
Capacitance (Input to Output)[1]	C_{I-O}		1.0		pF	f = 1 MHz
Input Capacitance[2]	C_I		4.0		pF	
IC Junction to Case Thermal Resistance	θ_{JC}		75		°C/W	Thermocouple located at center of package underside

[1] The device is considered a 2-terminal device: Pin 1 through Pin 8 are shorted together, and Pin 9 through Pin 16 are shorted together.
[2] Input capacitance is from any input data pin to ground.

REGULATORY INFORMATION

The ADuM3154 is pending approval by the organizations listed in Table 11. See Table 16 and the Insulation Lifetime section for recommended maximum working voltages for specific cross isolation waveforms and insulation levels.

Table 11.

UL (Pending)	CSA (Pending)	VDE (Pending)
Recognized under 1577 Component Recognition Program[1]	Approved under CSA Component Acceptance Notice #5A	Certified according to DIN V VDE V 0884-10 (VDE V 0884-10):2006-12[2]
3750 V RMS Single Protection	Basic insulation per CSA 60950-1-07 and IEC 60950-1, second edition, 510 V rms (721 V peak) maximum working voltage[3]	Reinforced insulation, 560 V peak
File E214100	File 205078	File 2471900-4880-0001

[1] In accordance with UL 1577, each ADuM3154 is proof tested by applying an insulation test voltage ≥1200 V rms for 1 sec (current leakage detection limit = 5 μA).
[2] In accordance with DIN V VDE V 0884-10, each ADuM3154 is proof tested by applying an insulation test voltage ≥525 V peak for 1 second (partial discharge detection limit = 5 pC). The asterisk (*) marked on the component designates DIN V VDE V 0884-10 approval.
[3] See Table 16 for recommended maximum working voltages under various operating conditions.

INSULATION AND SAFETY RELATED SPECIFICATIONS

Table 12.

Parameter	Symbol	Value	Unit	Test Conditions/Comments
Rated Dielectric Insulation Voltage		3750	V rms	1-minute duration
Minimum External Air Gap (Clearance)	L(I01)	5.1	mm min	Measured from input terminals to output terminals, shortest distance through air
Minimum External Tracking (Creepage)	L(I02)	5.1	mm min	Measured from input terminals to output terminals, shortest distance path along body
Minimum Internal Gap (Internal Clearance)		0.017	mm min	Insulation distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>400	V	DIN IEC 112/VDE 0303 Part 1
Material Group		II		Material group (DIN VDE 0110, 1/89, Table 1)

DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 INSULATION CHARACTERISTICS

This isolator is suitable for reinforced electrical isolation only within the safety limit data. Maintenance of the safety data is ensured by protective circuits. The asterisk (*) marked on packages denotes DIN V VDE V 0884-10 approval.

Table 13.

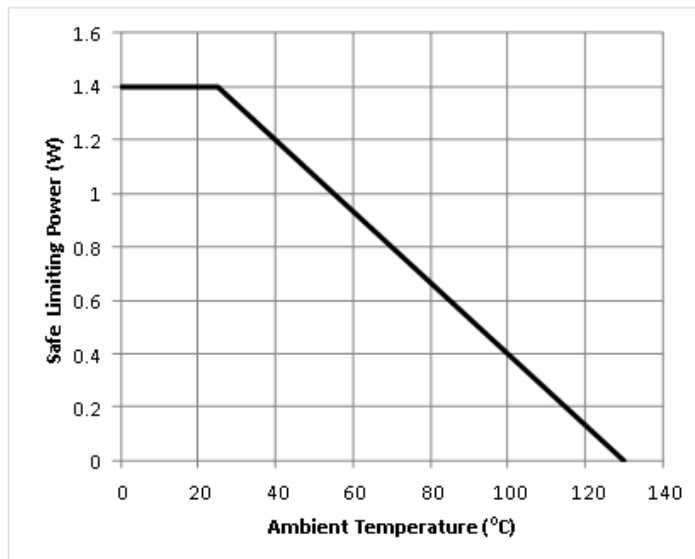| Description	Test Conditions/Comments	Symbol	Characteristic	Unit
Installation Classification per DIN VDE 0110				
For Rated Mains Voltage ≤ 150 V rms			I to IV	
For Rated Mains Voltage ≤ 300 V rms			I to III	
For Rated Mains Voltage ≤ 400 V rms			I to II	
Climatic Classification			40/105/21	
Pollution Degree per DIN VDE 0110, Table 1			2	
Maximum Working Insulation Voltage		V_{IORM}	560	V peak
Input-to-Output Test Voltage, Method b1	$V_{IORM} \times 1.875 = V_{pd(m)}$, 100% production test, $t_{ini} = t_m = 1$ sec, partial discharge < 5 pC	$V_{pd(m)}$	1050	V peak
Input-to-Output Test Voltage, Method a				
After Environmental Tests Subgroup 1	$V_{IORM} \times 1.5 = V_{pd(m)}$, $t_{ini} = 60$ sec, $t_m = 10$ sec, partial discharge < 5 pC	$V_{pd(m)}$	840	V peak
After Input and/or Safety Test Subgroup 2 and Subgroup 3	$V_{IORM} \times 1.2 = V_{pd(m)}$, $t_{ini} = 60$ sec, $t_m = 10$ sec, partial discharge < 5 pC	$V_{pd(m)}$	672	V peak
Highest Allowable Overvoltage		V_{IOTM}	5300	V peak
Surge Isolation Voltage	$V_{IOSM(TEST)} = 10$ kV, 1.2 µs rise time, 50 µs, 50% fall time	V_{IOSM}	6000	V peak
Safety Limiting Values	Maximum value allowed in the event of a failure (see Figure 2)			
Case Temperature		T_S	130	°C
Safety Total Dissipated Power		I_{S1}	1.4	W
Insulation Resistance at T_S	$V_{IO} = 500$ V	R_S	>10^9	Ω

Figure 2. Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN V VDE V 0884-10

RECOMMENDED OPERATING CONDITIONS

Table 14.

Parameter	Symbol	Min	Max	Unit
Operating Temperature Range	T_A	−40	+125	°C
Supply Voltage Range[1]	V_{DD1}, V_{DD2}	3.0	5.5	V
Input Signal Rise and Fall Times			1.0	ms

[1] See the DC Correctness and Magnetic Field Immunity section for information on the immunity to the external magnetic fields.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted

Table 15.

Parameter	Rating
Storage Temperature (T_{ST}) Range	−65°C to +150°C
Ambient Operating Temperature (T_A) Range	−40°C to +125°C
Supply Voltages (V_{DD1}, V_{DD2})	−0.5 V to +7.0 V
Input Voltages (MCLK, $\overline{MSS}$, MO, SO, SSA0, SSA1)	−0.5 V to V_{DD1} + 0.5 V
Output Voltages (SCLK, MI, SI, SS0 SS1, SS2, SS3)	−0.5 V to V_{DD2} + 0.5 V
Average Output Current per Pin[1]	−10 mA to +10 mA
Common-Mode Transients[2]	−100 kV/µs to +100 kV/µs

[1] See Figure 2 for maximum safety rated current values across temperature.
[2] Refers to common-mode transients across the insulation barrier. Common-mode transients exceeding the absolute maximum ratings may cause latch-up or permanent damage.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Table 16. Maximum Continuous Working Voltage[1]

Parameter	Max	Unit	Constraint
AC 60 Hz RMS Voltage	400	V rms	20-year lifetime at 0.1% failure rate, zero average voltage
DC Voltage	722	V peak	Limited by the creepage of the package, Pollution Degree 2, Material Group II[2, 3]

[1] See the Insulation Lifetime section for more details.
[2] Other pollution degree and material group requirements yield a different limit.
[3] Some system level standards allow components to use the printed wiring board (PWB) creepage values. The supported dc voltage may be higher for those standards.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.
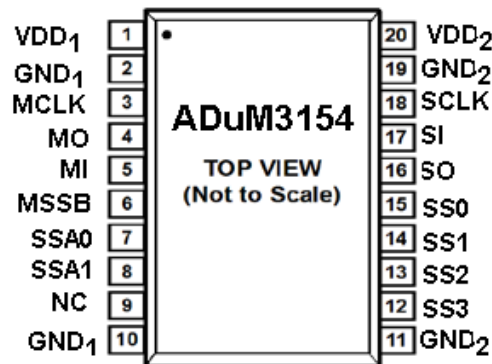
PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

Figure 3. Pin Configuration

Table 17. Pin Function Descriptions

Pin No.	Mnemonic	Direction	Description
1	V_{DD1}	Power	Input Power Supply for Side 1. A bypass capacitor to local ground is required.
2, 10	GND_1	Return	Ground 1. Ground reference for Isolator Side 1.
3	MCLK	Clock	SPI Clock from the Master Controller.
4	MO	Input	SPI Data from the Master MO/SI Line.
5	MI	Output	SPI Data from the Slave to the Master MI/SO Line.
6	$\overline{MSS}$	Input	Slave Select from the Master. This signal uses active low logic. Slave select requires a setup time from the next clock or data edge.
7	SSA0	Input	Multiplexer Selection Input, Low Order Bit.
8	SSA1	Input	Multiplexer Selection Input, High Order Bit.
9	NIC		Not Internally Connected. This pin is not internally connected and serves no function in the ADuM3154.
11, 19	GND_2	Return	Ground 2. Ground reference for Isolator Side 2.
12	SS3	Output	Routed Slave Select Signal. High-Z when SS3 is not selected.
13	SS2	Output	Routed Slave Select Signal. High-Z when SS2 is not selected.
14	SS1	Output	Routed Slave Select Signal. High-Z when SS1 is not selected.
15	SS0	Output	Routed Slave Select Signal. High-Z when SS0 is not selected.
16	SO	Input	SPI Data from the Slave to the Master MI/SO Line.
17	SI	Output	SPI Data from the Master to the Slave MO/SI Line.
18	SCLK	Output	SPI Clock from the Master Controller.
20	V_{DD2}	Power	Input Power Supply for Side 2. A bypass capacitor to local ground is required.

Table 18. Truth Table Abbreviations

Letter	Description
I	Indeterminate
X	Irrelevant
Z	High impedance

Table 19. Multiplexer Select Truth Table

Master Mux Inputs			Slave Mux Outputs			
$\overline{\text{MSS}}$	SSA0	SSA1	SS0	SS1	SS2	SS3
1	0	0	1	Z	Z	Z
0	0	0	0	Z	Z	Z
1	1	0	Z	1	Z	Z
0	1	0	Z	0	Z	Z
1	0	1	Z	Z	1	Z
0	0	1	Z	Z	0	Z
1	1	1	Z	Z	Z	1
0	1	1	Z	Z	Z	0

Table 20. Power Off Default State Truth Table (Positive Logic)

Master Side				Slave Side			
Power State	Output	Inputs		Power State	Input	Outputs	
V_{DD1}	MI	MCLK	MO	V_{DD2}	SO	SCLK	SI
Unpowered[1]	Z	X	X	Powered	X	Z	Z
Powered	Z	X	X	Unpowered[1]	X	Z	Z
Powered	1	1	1	Powered	1	1	1
Powered	0	0	0	Powered	0	0	0

[1] Outputs on an unpowered side are high impedance within one diode drop of ground.

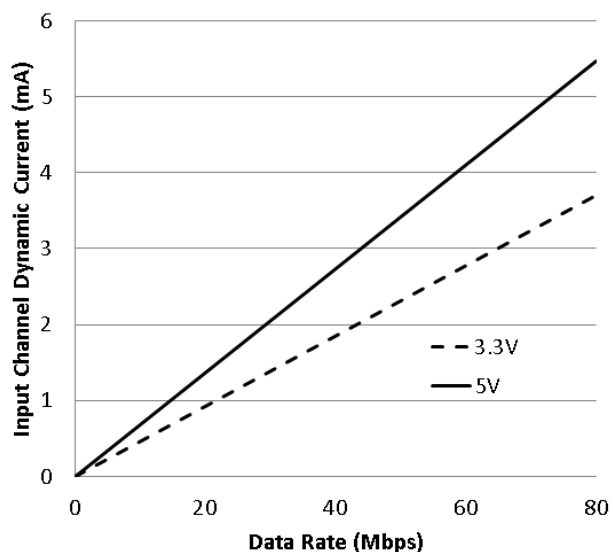# TYPICAL PERFORMANCE CHARACTERISTICS

Figure 4. Typical Dynamic Supply Current per Input Channel vs. Data Rate
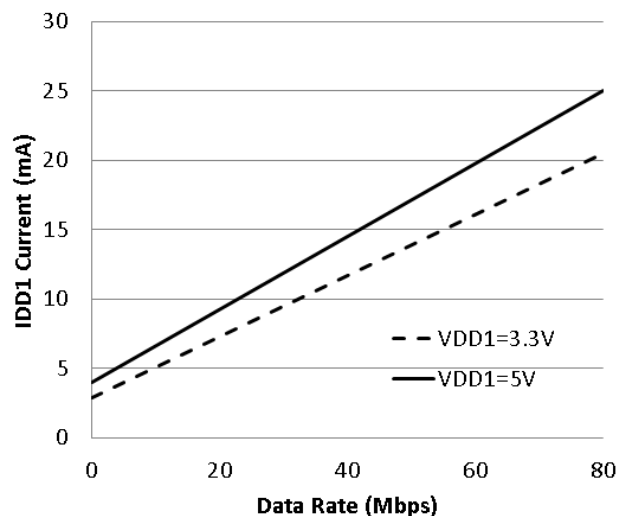for 5 V and 3.3 V Operation

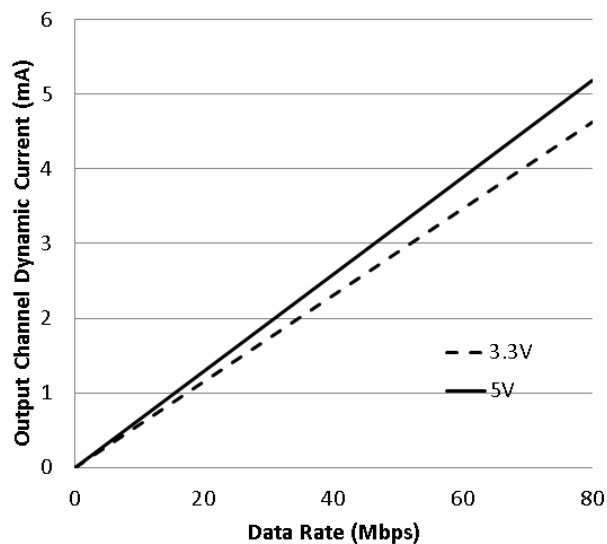Figure 6. Typical I_{DD1} Supply Current vs. Data Rate for 5 V and 3 V Operation

Figure 5. Typical Dynamic Supply Current per Output Channel vs. Data Rate
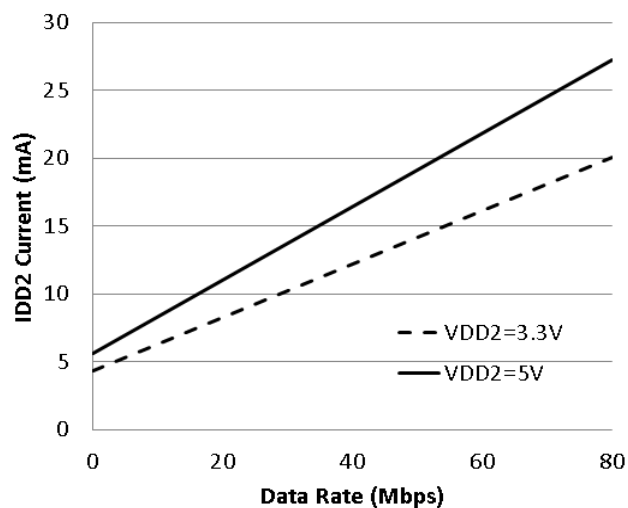for 5 V and 3.3 V Operation

Figure 7. Typical I_{DD2} Supply Current vs. Data Rate for 5 V and 3 V Operation
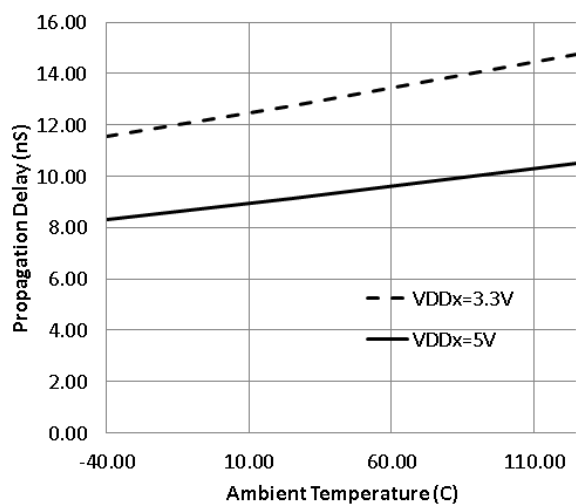
Figure 8. Typical Propagation Delay vs. Ambient Temperature for High Speed Channels Without Glitch Filter (See the High Speed Channels Section for Additional Information)
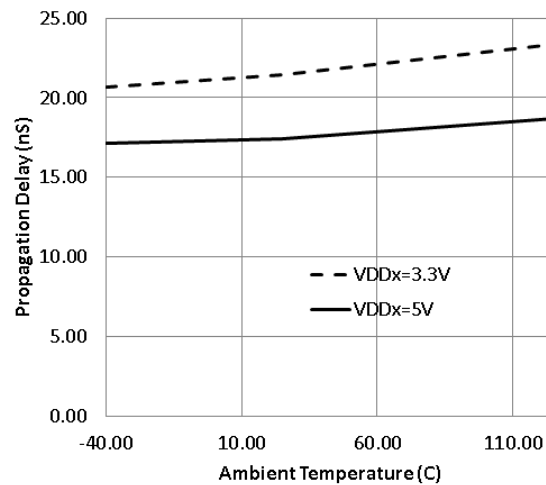

Figure 9. Typical Propagation Delay vs. Ambient Temperature for High Speed Channels with Glitch Filter (See the High Speed Channels Section for Additional Information)

APPLICATIONS INFORMATION

INTRODUCTION

The ADuM3154 was created to optimize isolation of the SPI for speed and provide additional low speed channels for control and status monitoring functions. The isolator is based on differential signaling *i*Coupler technology for enhanced speed and noise immunity.

High Speed Channels

The ADuM3154 has four high speed channels. The first three, CLK, MI/SO, and MO/SI (the slash indicates the connection of the particular input and output channel across the isolator), are optimized for either low propagation delay in the B grade, or high noise immunity in the A grade. The difference between the grades is the addition of a glitch filter to these three channels in the A grade version, which increases propagation delay. The B grade version, with a maximum propagation delay of 14 ns, supports a maximum clock rate of 17 MHz in standard 4-wire SPI. However, because the glitch filter is not present in the B grade version, ensure that spurious glitches of less than 10 ns are not present.

Glitches of less than 10 ns in the B grade devices can cause the second edge of the glitch to be missed. This pulse condition is seen as a spurious data transition on the output that is corrected by refresh or the next valid data edge. It is recommended to use A grade devices in noisy environments.

The relationship between the SPI signal paths and the pin mnemonic of the ADuM3154 and data directions is summarized in Table 21.

Table 21. Pin Mnemonic Correspondence to SPI Signal Path Names

SPI Signal Path	Master Side 1	Data Direction	Slave Side 2
CLK	MCLK	→	SCLK
MO/SI	MO	→	SI
MI/SO	MI	←	SO
$\overline{SS}$	$\overline{MSS}$	→	SSx

The datapaths are SPI mode agnostic. The CLK and MO/SI channels are optimized for propagation delay and channel to channel matching. The device does not synchronize to the clock channel; therefore, there are no constraints on the clock polarity or the timing with respect to the data line.

The $\overline{SS}$ (slave select bar) is typically an active low signal. It can have many different functions in SPI and SPI like busses. Many of these functions are edge triggered, so the $\overline{SS}$ path contains a glitch filter in both the A grade and the B grade. The glitch filter prevents short pulses from propagating to the output or causing other errors in operation. The $\overline{MSS}$ signal requires a 10 ns setup time in the B grade devices prior to the first active clock edge to allow the added propagation time of the glitch filter.

Slave Select Multiplexer

The ADuM3154 can control up to four independent slave devices. Figure 10 shows how this can be done using general-purpose isolators. An isolation channel is required for each slave select; therefore, a total of seven high speed channels are required to transfer bidirectional data to four slaves.
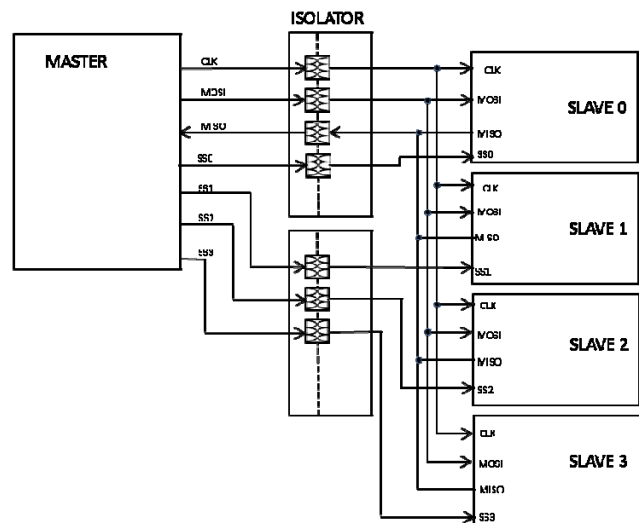

Figure 10. Multiple Slave Control with Standard Isolators

Figure 11 shows how the ADuM3154 can control up to four slaves by routing the $\overline{MSS}$ input to one of four outputs on the slave side of the isolator, which eliminates three isolation channels compared to the standard solution.
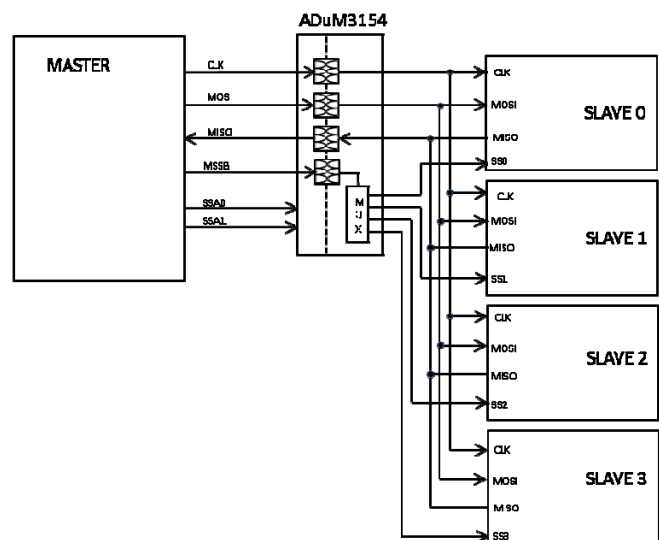

Figure 11. Multiple Slave Control

The multiplexer select lines are low speed channels implemented as part of the dc correctness scheme in the ADuM3154. The dc value of all high and low speed inputs on a given side of the device are sampled simultaneously, packetized, and shifted across an isolation coil. The high speed channels are compared for dc accuracy, and the low speed mux select lines, SSA0 and

SSA1, are transferred to the mux control block. The dc correctness data for the high speed channels is handled internally with no visibility off chip.

This data is regulated by a free running internal clock. Because data is sampled at discrete times based on this clock, the propagation delay for mux select lines is between 400 ns and 1.7 μs depending on where the input data edge changes with respect to the internal sample clock. After the 1.7 μs setup time, the multiplexer routes $\overline{MSS}$ signals to the desired output. The outputs that are not selected are set to high-Z, and the application pulls them to the desired idle state.

Figure 12 illustrates the behavior of SSA0 and SSA1 channels. This diagram assumes that $\overline{MSS}$ is low and that SS0, SS1, SS2, and SS3 are pulled up.
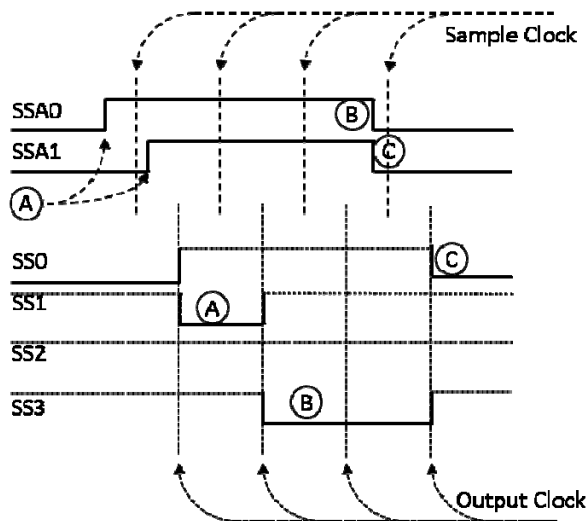

Figure 12. Mux Select Timing

- Point A: The mux select lines must be switched simultaneously to within the $V_{Ix\,SKEW}$ time. Failure to do this may allow sampling the inputs between the edges and selecting an incorrect mux output. Point A on SS1 is a metastable state on the output mux resulting from wide spacing between SSA0 and SSA1.

- Point B: For mux select lines to be processed predictably, a state of SSA0 and SSA1 must be stable for longer than 4 μs before switching the mux to another output. This guarantees that at least two samples are taken of the inputs before the mux output is changed.

- Point C: This point in Figure 12 shows a clean transfer between SS3 being active and SS0 being active. The mux was designed to eliminate any short duration metastable states between any two selected outputs.

PRINTED CIRCUIT BOARD (PCB) LAYOUT

The ADuM3154 digital isolator requires no external interface circuitry for the logic interfaces. Power supply bypassing is strongly recommended at both input and output supply pins, V_{DD1} and V_{DD2} (see Figure 13). The capacitor value must be between 0.01 μF and 0.1 μF. The total lead length between both ends of the capacitor and the input power supply pin must not exceed 20 mm.
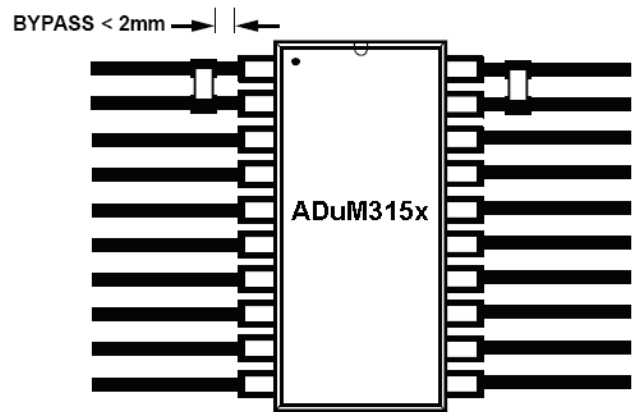

Figure 13. Recommended PCB Layout

In applications involving high common-mode transients, it is important to minimize board coupling across the isolation barrier. Furthermore, design the board layout so that any coupling that does occur affects all pins equally on a given component side. Failure to ensure this can cause voltage differentials between pins exceeding the absolute maximum ratings of the device, thereby leading to latch-up or permanent damage.

PROPAGATION DELAY RELATED PARAMETERS

Propagation delay is a parameter that describes the time it takes a logic signal to propagate through a component. The input to output propagation delay time for a high to low transition may differ from the propagation delay time of a low to high transition.
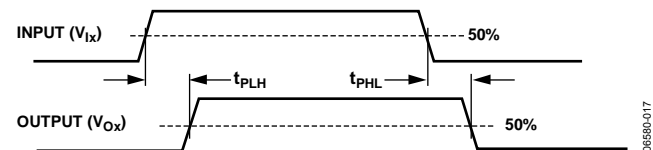

Figure 14. Propagation Delay Parameters

Pulse width distortion is the maximum difference between these two propagation delay values and an indication of how accurately the timing of the input signal is preserved.

Channel to channel matching refers to the maximum amount the propagation delay differs between channels within a single ADuM3154 component.

DC CORRECTNESS AND MAGNETIC FIELD IMMUNITY

Positive and negative logic transitions at the isolator input cause narrow (~1 ns) pulses to be sent via the transformer to the decoder. The decoder is bistable and is, therefore, either set or reset by the pulses indicating input logic transitions. In the absence of logic transitions at the input for more than ~1.2 μs, a periodic set of refresh pulses indicative of the correct input state are sent via the low speed channel to ensure dc correctness at the output.

If the low speed decoder receives no pulses for more than about 5 μs, the input side is assumed to be unpowered or nonfunctional, in which case, the isolator output is forced to a default low state by the watchdog timer circuit.

The limitation on the magnetic field immunity of the device is set by the condition in which induced voltage in the transformer receiving coil is sufficiently large to either falsely set or reset the decoder. The following analysis defines such conditions. The ADuM3154 is examined in a 3 V operating condition because it represents the most susceptible mode of operation of this product.

The pulses at the transformer output have amplitude greater than 1.5 V. The decoder has a sensing threshold of about 1.0 V; therefore establishing a 0.5 V margin in which induced voltages can be tolerated. The voltage induced across the receiving coil is given by

$$V = (-d\beta/dt)\Sigma\pi r_n^2; \; n = 1, 2, \ldots, N$$

where:
β is the magnetic flux density.
r_n is the radius of the nth turn in the receiving coil.
N is the number of turns in the receiving coil.

Given the geometry of the receiving coil in the ADuM3154 and an imposed requirement that the induced voltage be, at most, 50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated, as shown in Figure 15.
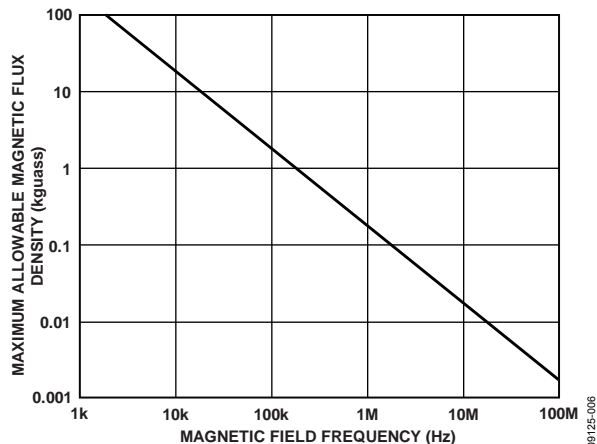
Figure 15. Maximum Allowable External Magnetic Flux Density

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.5 kgauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and does not cause a faulty output transition. If such an event occurs, with the worst-case polarity, during a transmitted pulse, it reduces the received pulse from >1.0 V to 0.75 V, which is still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances away from the ADuM3154 transformers. Figure 16 expresses these allowable current magnitudes as a function of frequency for selected distances. The ADuM3154 is very insensitive to external fields. Only extremely large, high frequency currents very close to the component may potentially be a concern. For the 1 MHz example noted, a user would have to place a 1.2 kA current 5 mm away from the ADuM3154 to affect component operation.
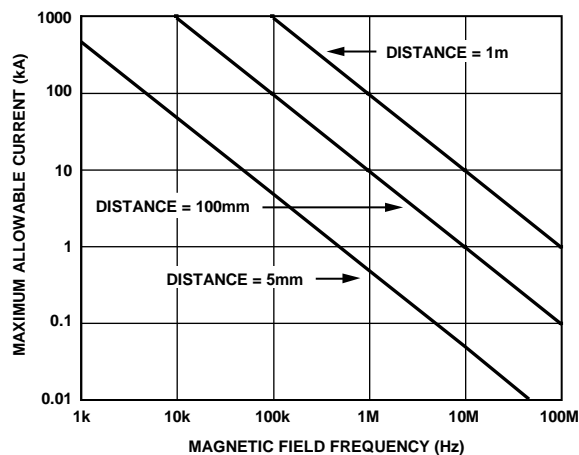
Figure 16. Maximum Allowable Current for Various Current to ADuM3154 Spacings

Note that at combinations of strong magnetic field and high frequency, any loops formed by PCB traces may induce sufficiently large error voltages to trigger the thresholds of succeeding circuitry. Take care to avoid PCB structures that form loops.

POWER CONSUMPTION

The supply current at a given channel of the ADuM3154 isolator is a function of the supply voltage, the data rate of the channel, and the output load of the channel and whether it is a high or low speed channel.

The low speed channels draw a constant quiescent current due to the ping-pong datapath internally. The operating frequency is low enough that the capacitive losses due to the recommended capacitive load are negligible compared to the quiescent current. The explicit calculation for the data rate is eliminated for simplicity, and the quiescent current for each side of the isolator due to the low speed channels can be found in Table 3, Table 5, Table 7, and Table 9 for the particular operating voltages. Add these quiescent currents to the high speed current calculated in the following equations for the total current for each side of the isolator.

For each high speed input channel, the supply current is given by

$$I_{DDI} = I_{DDI(D)} \times f + I_{DDI(Q)}$$

For each high speed output channel, the supply current is given by

$$I_{DDO} = (I_{DDO(D)} + (0.5 \times 10^{-3}) \times C_L \times V_{DDO}) \times f + I_{DDO(Q)}$$

where:
$I_{DDI(D)}$, $I_{DDO(D)}$ are the input and output dynamic supply currents per channel (mA/Mbps).
C_L is the output load capacitance (pF).
V_{DDO} is the output supply voltage (V).
f is the input logic signal data rate, expressed in units of Mbps.
$I_{DDI(Q)}$, $I_{DDO(Q)}$ are the specified input and output quiescent supply currents (mA).

To calculate the total V_{DD1} and V_{DD2} supply current, the supply currents for each input and output channel corresponding to V_{DD1} and V_{DD2} are calculated and totaled. Figure 4 and Figure 5 show the per channel supply currents as a function of data rate for an unloaded output condition. Figure 6 and Figure 7 show the total V_{DD1} and V_{DD2} supply current as a function of data rate for ADuM3154 channel configurations with all high speed channels running at the same data rate and the low speed channels at idle.

INSULATION LIFETIME

All insulation structures eventually break down when subjected to voltage stress over a sufficiently long period. The rate of insulation degradation is dependent on the characteristics of the voltage waveform applied across the insulation, as well as the materials and material interfaces.

There are two types of insulation degradation of primary interest: breakdown along surfaces exposed to the air and insulation wear out. Surface breakdown is the phenomenon of surface tracking and the primary determinant of surface creepage requirements in system level standards. Insulation wear out is the phenomenon where charge injection or displacement currents inside the insulation material cause long-term insulation degradation.

Surface Tracking

Surface tracking is addressed in electrical safety standards by setting a minimum surface creepage based on the working voltage, the environmental conditions, and the properties of the insulation material. Safety agencies perform characterization testing on the surface insulation of components that allows the components to be categorized in different material groups. Lower material group ratings are more resistant to surface tracking and therefore can provide adequate lifetime with smaller creepage. The minimum creepage for a given working voltage and material group is in each system level standard and is based on the total rms voltage across the isolation, pollution degree, and material group. The material group and creepage for the ADuM3154 isolator are presented in Table 12.

Insulation Wear Out

The lifetime of insulation due to wear out is determined by its thickness, the material properties, and the voltage stress applied. It is important to verify that the product lifetime is adequate at the application working voltage. The working voltage supported by an isolator for wear out may not be the same as the working voltage supported for tracking. It is the working voltage applicable to tracking that is specified in most standards.

Testing and modeling have shown that the primary driver of long-term degradation is displacement current in the polyimide insulation causing incremental damage. The stress on the insulation can be broken down into two broad categories: dc stress, which causes very little wear out because there is no displacement current, and an ac component time varying voltage stress, which causes wear out.

The ratings in certification documents are usually based on 60 Hz sinusoidal stress, because this reflects isolation from line voltage. However, many practical applications have combinations of 60 Hz ac and dc across the barrier, as shown in Equation 1. Because only the ac portion of the stress causes wear out, the equation can be rearranged to solve for the ac rms voltage, as shown in Equation 2. For insulation wear out with the polyimide materials used in this product, the ac rms voltage determines product lifetime.

$$V_{RMS} = \sqrt{V_{AC\ RMS}{}^2 + V_{DC}{}^2} \qquad (1)$$

or

$$V_{AC\ RMS} = \sqrt{V_{RMS}{}^2 - V_{DC}{}^2} \qquad (2)$$

where:
$V_{AC\ RMS}$ is the time varying potion of the working voltage.
V_{DC} is the dc offset of the working voltage.
V_{RMS} is the total rms working voltage of the working voltage.

Calculation and Use of Parameters Example

The following is an example that frequently arises in power conversion applications. Assume that the line voltage on one side of the isolation is 240 V ac rms, and a 400 V dc bus voltage is present on the other side of the isolation barrier. The isolator material is polyimide. To establish the critical voltages in determining the creepage clearance and lifetime of a device, see Figure 17 and the following equations.
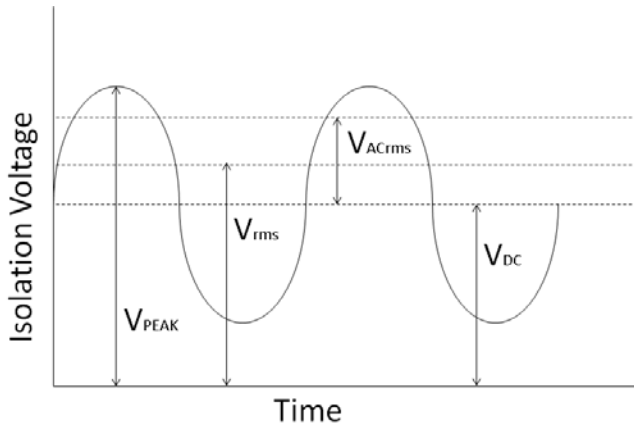

Figure 17. Critical Voltage Example

The working voltage across the barrier from Equation 1 is

$$V_{RMS} = \sqrt{V_{AC\ RMS}^2 + V_{DC}^2}$$

$$V_{RMS} = \sqrt{240^2 + 400^2}$$

$$V_{RMS} = 466 \text{ V}$$

The result of the previous equation is the working voltage used along with the material group and pollution degree when looking up the creepage required by a system standard.

To determine if the lifetime is adequate, obtain the time varying portion of the working voltage. The ac rms voltage can be obtained from Equation 2.

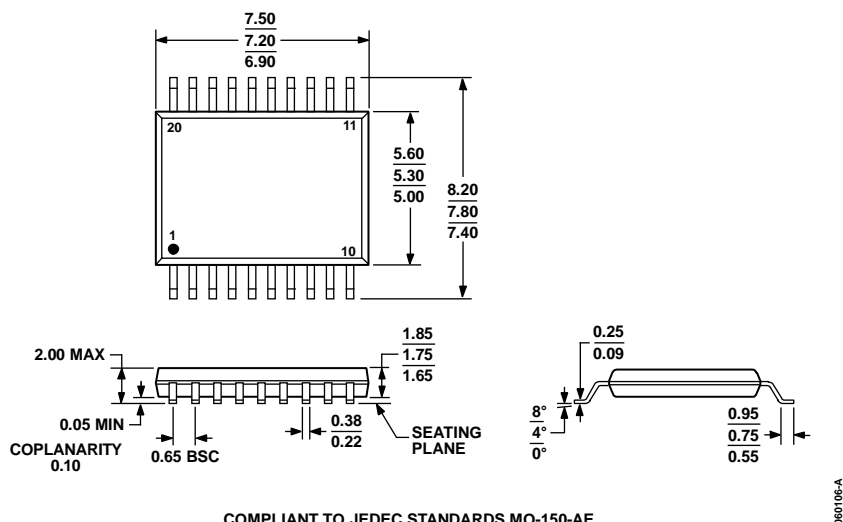$$V_{AC\ RMS} = \sqrt{V_{RMS}^2 - V_{DC}^2}$$

$$V_{AC\ RMS} = \sqrt{466^2 - 400^2}$$

$$V_{AC\ RMS} = 240 \text{ V rms}$$

In this case, the ac rms voltage is simply the line voltage of 240 V rms. This calculation is more relevant when the waveform is not sinusoidal. The value is compared to the limits for the working voltage listed in Table 16 for the expected lifetime, under a 60 Hz sine wave, and it is well within the limit for a 50-year service life.

Note that the dc working voltage limit in Table 16 is set by the creepage of the package as specified in IEC 60664-1. This value may differ for specific system level standards.

OUTLINE DIMENSIONS

COMPLIANT TO JEDEC STANDARDS MO-150-AE

Figure 18. 20-Lead Shrink Small Outline Package [SSOP]
(RS-20)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	No. of Inputs, V_{DD1} Side	No. of Inputs, V_{DD2} Side	Maximum Data Rate (MHz)	Maximum Propagation Delay, 5 V (ns)	Isolation Rating (V ac)	Temperature Range	Package Description	Package Option
ADuM3154ARSZ	5	1	1	25	3750	−40°C to +125°C	20-Lead SSOP	RS-20
ADuM3154ARSZ-RL7	5	1	1	25	3750	−40°C to +125°C	20-Lead SSOP, 7" Reel	RS-20
ADuM3154BRSZ	5	1	17	14	3750	−40°C to +125°C	20-Lead SSOP	RS-20
ADuM3154BRSZ-RL7	5	1	17	14	3750	−40°C to +125°C	20-Lead SSOP, 7" Reel	RS-20
EVAL-ADuM3154Z							Evaluation Board	

[1] Z = RoHS Compliant Part.

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